

MOS FIELD EFFECT TRANSISTOR 2SK3360

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3360 is N-Channel MOS Field Effect Transistor designed for high current switching application.

FEATURES

- Low on-state resistance
- ★ $R_{DS(on)1} = 30 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, \text{ ID} = 18 \text{ A})$
- ★ $R_{DS(on)2} = 40 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4.5 \text{ V}, \text{ ID} = 18 \text{ A})$
- ★ Low Ciss: Ciss = 3200 pF TYP.
 - Built-in gate protection diode
 - Isolated TO-220 package

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

	Drain to Source Voltage	VDSS	100	V
	Gate to Source Voltage	VGSS(AC)	±20	V
	Gate to Source Voltage	VGSS(DC)	+20, –10	V
\star	Drain Current (DC)	D(DC)	±35	А
\star	Drain Current (pulse) Note1	D(pulse)	±140	А
	Total Power Dissipation (Tc = 25°C)	Рт	35	W
	Total Power Dissipation (TA = 25°C)	Р⊤	2.0	W
	Channel Temperature	Tch	150	°C
	Storage Temperature	Tstg	-55 to +150	°C
\star	Single Avalanche Current Note2	AS	35	А
\star	Single Avalanche Energy Note2	Eas	122	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %

2. Starting $T_{ch} = 25 \text{ °C}$, $R_G = 25 \Omega$, $V_{GS} = 20 \text{ V} \rightarrow 0 \text{ V}$

THERMAL RESISTANCE

Channel to Case	Rth(ch-C)	3.57	°C/W
Channel to Ambient	Rth(ch-A)	62.5	°C/W

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ORDERING INFORMATION

PART NUMBER	PACKAGE	
2SK3360	Isolated TO-220	



(Isolated TO-220)

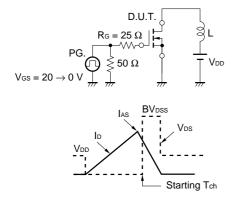
* ELECTRICAL CHARACTERISTICS (TA = 25 °C)

NEC

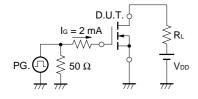
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 18 A		20	30	mΩ
	RDS(on)2	Vgs = 4.5 V, Id = 18 A		28	40	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = 10 \text{ V}, \text{ ID} = 250 \mu\text{A}$	1.5	2.0	2.5	V
Forward Transfer Admittance	y _{fs}	Vds = 10 V, Id = 18 A	13	28		S
Drain Leakage Current	IDSS	Vds = 100 V, Vgs = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	Vds = 10 V		3200		pF
Output Capacitance	Coss	Vgs = 0 V		640		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		360		pF
Turn-on Delay Time	td(on)	ID = 18 A		35		ns
Rise Time	tr	VGS(on) = 10 V		220		ns
Turn-off Delay Time	$t_{d(off)}$	Vdd = 50 V		220		ns
Fall Time	tr	R _G = 10 Ω		190		ns
Total Gate Charge	QG	ID = 35 A		84		nC
Gate to Source Charge	QGS	Vdd = 80 V		11		nC
Gate to Drain Charge	Qgd	VGS(on) = 10 V		31		nC
Body Diode Forward Voltage	VF(S-D)	IF = 35 A, VGS = 0 V		0.96		V
Reverse Recovery Time	trr	IF = 35 A, VGS = 0 V		150		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		800		nC

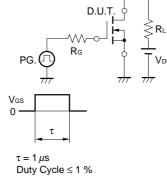
TEST CIRCUIT 1 AVALANCHE CAPABILITY

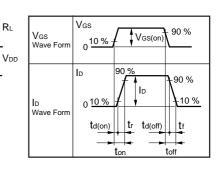
TEST CIRCUIT 2 SWITCHING TIME



TEST CIRCUIT 3 GATE CHARGE



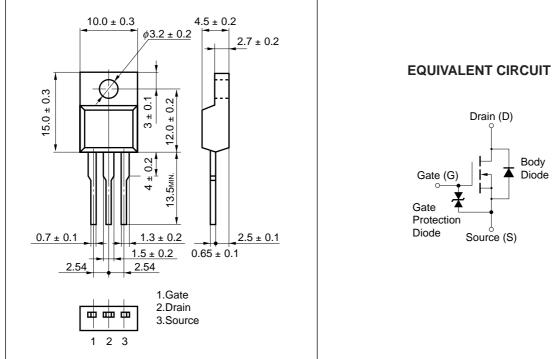


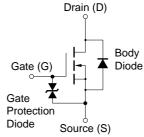


Preliminary Data Sheet D14331EJ1V0DS00

PACKAGE DRAWING (Unit : mm)

Isolated TO-220 (MP-45F)





Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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